Low-power configurable multiple function gate Rev. 7 — 16 September 2015 P

Product data sheet

General description 1.

The 74AUP1G57 provides configurable multiple functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions AND, OR, NAND, NOR, XNOR, inverter, and buffer. All inputs can be connected to V_{CC} or GND.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using IOFF. The IOFF circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74AUP1G57 has Schmitt trigger inputs making it capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_H.

Features and benefits 2.

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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3. Ordering information

Table 1. Ordering information

| Type number | Package | | | | | | |
|-------------|-------------------|--------|---|---------|--|--|--|
| | Temperature range | Name | e Description | | | | |
| 74AUP1G57GW | –40 °C to +125 °C | SC-88 | plastic surface-mounted package; 6 leads | SOT363 | | | |
| 74AUP1G57GM | –40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm | SOT886 | | | |
| 74AUP1G57GF | –40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm | SOT891 | | | |
| 74AUP1G57GN | –40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm | SOT1115 | | | |
| 74AUP1G57GS | –40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm | SOT1202 | | | |
| 74AUP1G57GX | –40 °C to +125 °C | X2SON6 | plastic thermal extremely thin small outline package; no leads; 6 terminals; body 1 \times 0.8 \times 0.35 mm | SOT1255 | | | |

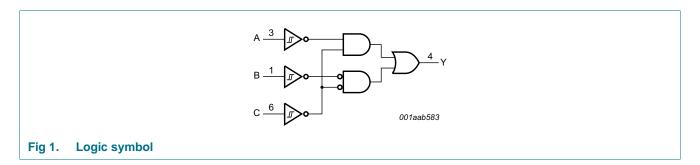
4. Marking

Table 2. Marking

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| 74AUP1G57GW | aC |
| 74AUP1G57GM | aC |
| 74AUP1G57GF | aC |
| 74AUP1G57GN | aC |
| 74AUP1G57GS | aC |
| 74AUP1G57GX | aC |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

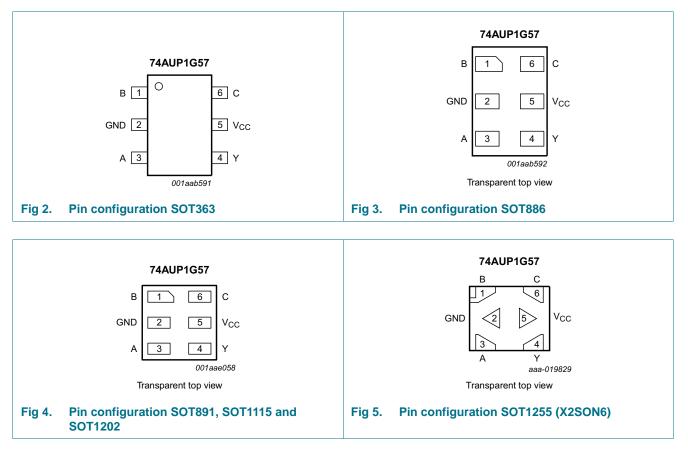
5. Functional diagram



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6. Pinning information

6.1 Pinning



6.2 Pin description

| Table 3. Pin description | | | | | | | |
|--------------------------|-----|----------------|--|--|--|--|--|
| Symbol | Pin | Description | | | | | |
| В | 1 | data input | | | | | |
| GND | 2 | ground (0 V) | | | | | |
| A | 3 | data input | | | | | |
| Y | 4 | data output | | | | | |
| V _{CC} | 5 | supply voltage | | | | | |
| С | 6 | data input | | | | | |

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7. Functional description

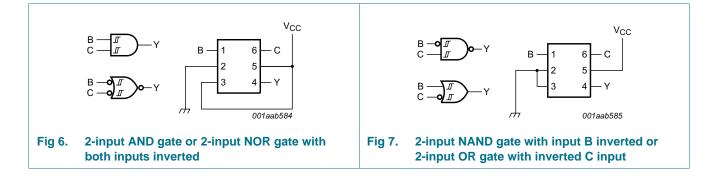
| Table 4. Functio | n table ^[1] | | |
|------------------|------------------------|--------|---|
| Input | | Output | |
| C | В | A | Y |
| L | L | L | Н |
| L | L | Н | L |
| L | Н | L | Н |
| L | Н | Н | L |
| Н | L | L | L |
| Н | L | Н | L |
| Н | Н | L | Н |
| Н | Н | Н | Н |

[1] H = HIGH voltage level; L = LOW voltage level.

7.1 Logic configurations

Table 5.Function selection table

| Logic function | Figure |
|---------------------------------------|---|
| 2-input AND | see <u>Figure 6</u> |
| 2-input AND with both inputs inverted | see <u>Figure 9</u> |
| 2-input NAND with inverted input | see Figure 7 and Figure 8 |
| 2-input OR with inverted input | see <u>Figure 7</u> and <u>Figure 8</u> |
| 2-input NOR | see <u>Figure 9</u> |
| 2-input NOR with both inputs inverted | see <u>Figure 6</u> |
| 2-input XNOR | see Figure 10 |
| Inverter | see <u>Figure 11</u> |
| Buffer | see Figure 12 |



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NXP Semiconductors

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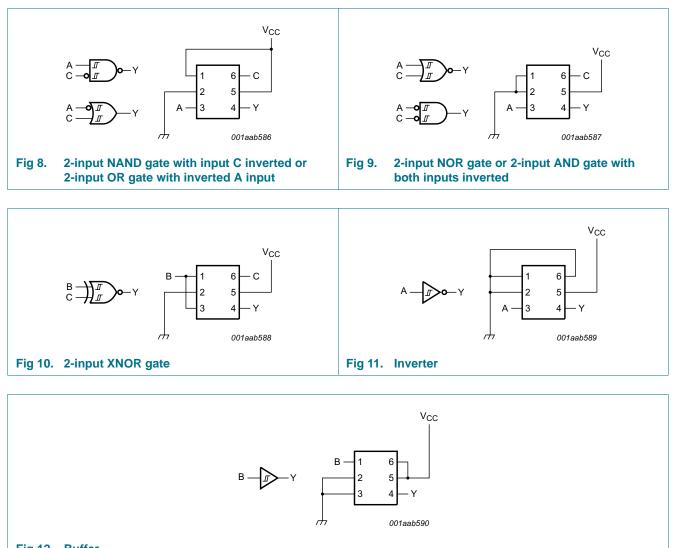


Fig 12. Buffer

8. Limiting values

Table 6.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|-----------------|-------------------------|----------------------------------|------------|------|------|------|
| V _{CC} | supply voltage | | | -0.5 | +4.6 | V |
| I _{IK} | input clamping current | V ₁ < 0 V | | -50 | - | mA |
| VI | input voltage | | <u>[1]</u> | -0.5 | +4.6 | V |
| I _{OK} | output clamping current | V _O < 0 V | | -50 | - | mA |
| Vo | output voltage | Active mode and Power-down mode | <u>[1]</u> | -0.5 | +4.6 | V |
| I _O | output current | $V_{O} = 0 V \text{ to } V_{CC}$ | | - | ±20 | mA |
| I _{CC} | supply current | | | - | 50 | mA |

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Unit

V

V V

∨ °C

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Table 6. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| | | | | | , |
|------------------|-------------------------|--|-----|------|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| I _{GND} | ground current | | -50 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ [2] | - | 250 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SC-88 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.
 For X2SON6 and XSON6 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max |
|------------------|---------------------|---------------------------------|-----|-----------------|
| V _{CC} | supply voltage | | 0.8 | 3.6 |
| VI | input voltage | | 0 | 3.6 |
| Vo | output voltage | Active mode | 0 | V _{CC} |
| | | Power-down mode; $V_{CC} = 0 V$ | 0 | 3.6 |
| T _{amb} | ambient temperature | | -40 | +125 |

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---------------------------|---|-----------------------|-----|--------------------|------|
| T _{amb} = 2 | 5 °C | | | | | _ |
| V _{OH} | HIGH-level output voltage | $V_{I} = V_{T+}$ or V_{T-} | | | | |
| | | I_{O} = –20 $\mu\text{A};V_{CC}$ = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | $0.75 \times V_{CC}$ | - | - | V |
| | | $I_0 = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | 1.11 | - | - | V |
| | | $I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | 1.32 | - | - | V |
| | | $I_0 = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 2.05 | - | - | V |
| | | $I_0 = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.9 | - | - | V |
| | | $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.72 | - | - | V |
| | | $I_{O} = -4.0 \text{ mA}; \text{ V}_{CC} = 3.0 \text{ V}$ | 2.6 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | $0.3\times V_{CC}$ | V |
| | | $I_{O} = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | - | - | 0.31 | V |
| | | I_{O} = 1.9 mA; V_{CC} = 1.65 V | - | - | 0.31 | V |
| | | $I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.31 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.44 | V |
| | | $I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.31 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.44 | V |

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Parameter Conditions Unit Symbol Min Тур Max input leakage current $V_{I} = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V ±0.1 μА h. -- V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V ±0.2 power-off leakage current **I**OFF -μΑ additional power-off leakage V_{I} or $V_{O} = 0$ V to 3.6 V; ΔI_{OFF} ±0.2 uΑ _ current $V_{CC} = 0 V \text{ to } 0.2 V$ supply current $V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ 0.5 I_{CC} μA -V_{CC} = 0.8 V to 3.6 V $V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A;$ 40 ΔI_{CC} additional supply current μA -- $V_{CC} = 3.3 V$ Cı $V_I = GND \text{ or } V_{CC}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$ pF input capacitance 1.1 -- $V_0 = GND; V_{CC} = 0 V$ Co output capacitance 1.7 pF -T_{amb} = -40 °C to +85 °C HIGH-level output voltage $V_I = V_{T+}$ or V_{T-} VOH $I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 0.8 \ \text{V} \text{ to } 3.6 \ \text{V}$ $V_{CC}-0.1$ V $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ $0.7 \times V_{CC}$ -V _ $I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ 1.03 V -- $I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ 1.30 V -_ $I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 1.97 V -- $I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 1.85 V -- $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ 2.67 V - $I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ 2.55 V -_ Vol LOW-level output voltage $V_I = V_{T+} \text{ or } V_{T-}$ $I_{O} = 20 \ \mu A$; $V_{CC} = 0.8 \ V$ to 3.6 V 0.1 V - $I_0 = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ V $0.3 \times V_{CC}$ -- $I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ 0.37 V -- $I_0 = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ 0.35 V -- $I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 0.33 V -- $I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ V 0.45 -- $I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ 0.33 V -- $I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ 0.45 V -- $V_{I} = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V I_L input leakage current ± 0.5 μΑ -_ power-off leakage current $V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$ ±0.5 μA **I**OFF -- $V_{I} \text{ or } V_{O} = 0 \text{ V to 3.6 V;}$ ΔI_{OFF} additional power-off leakage ±0.6 μΑ -_ current $V_{CC} = 0 V \text{ to } 0.2 V$ $V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ lcc supply current 0.9 uΑ -- $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ $V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A;$ 50 ΔI_{CC} additional supply current μA -- $V_{CC} = 3.3 V$ $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$

Static characteristics ... continued Table 8.

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

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Unit Symbol Parameter Conditions Max Min Тур HIGH-level output voltage $V_1 = V_{T+}$ or V_{T-} VOH $I_{O} = -20 \ \mu A$; $V_{CC} = 0.8 \ V$ to 3.6 V $V_{CC} - 0.11$ V -_ $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ V $0.6 \times V_{CC}$ -- $I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ 0.93 V -- $I_0 = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ 1.17 -V _ $I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 1.77 V -- $I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 1.67 V -- $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ 2.40 v -_ $I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ 2.30 V --LOW-level output voltage $V_I = V_{T+} \text{ or } V_{T-}$ VOL $I_{O} = 20 \ \mu A$; $V_{CC} = 0.8 \ V$ to 3.6 V V 0.11 _ - $I_0 = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ $0.33 \times V_{CC}$ V _ - $I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ 0.41 V -- $I_{O} = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ v 0.39 --V $I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 0.36 -- $I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 0.50 V -- $I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ v 0.36 -- $I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ V 0.50 -- $V_{I} = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V ±0.75 input leakage current μA I_L -power-off leakage current $V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$ ±0.75 μΑ **I**OFF -- $V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ ΔI_{OFF} additional power-off leakage --±0.75 μΑ current $V_{CC} = 0 V \text{ to } 0.2 V$ $V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ supply current 1.4 μA Icc -- $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ $V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A;$ additional supply current 75 ΔI_{CC} μΑ -_ $V_{CC} = 3.3 V$

Table 8. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

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11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 14.

| Symbol | Parameter | Conditions | | | 25 °C | | –40 °C to +125 °C | | | Unit |
|----------------------|-------------------|--|-----|-----|--------|------|-------------------|----------------|-----------------|------|
| | | | | Min | Typ[1] | Max | Min | Max (85 °C) | Max (125 °C) | |
| C _L = 5 p | F | | | | | | | | | |
| t _{pd} | propagation delay | A, B and C to Y; see <u>Figure 13</u> | [2] | | | | | | | |
| | | V _{CC} = 0.8 V | | - | 22.6 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | | 2.8 | 6.5 | 12.6 | 2.5 | 13.0 | 13.2 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 2.2 | 4.6 | 7.6 | 2.5 | 8.2 | 8.6 | ns |
| | | V_{CC} = 1.65 V to 1.95 V | | 2.1 | 3.9 | 6.2 | 2.0 | 6.8 | 7.2 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | | 2.0 | 3.1 | 4.5 | 1.8 | 5.1 | 5.3 | ns |
| | | V_{CC} = 3.0 V to 3.6 V | | 1.8 | 2.8 | 3.9 | 1.5 | 4.1 | 4.3 | ns |
| C _L = 10 | pF | 1 | _ | | | | | • | | - |
| t _{pd} | propagation delay | A, B and C to Y; see <u>Figure 13</u> | [2] | | | | | | | |
| | | V _{CC} = 0.8 V | | - | 26.1 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | | 3.2 | 7.3 | 14.4 | 2.8 | 14.9 | 15.2 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 2.6 | 5.2 | 8.7 | 2.8 | 9.3 | 9.8 | ns |
| | | V_{CC} = 1.65 V to 1.95 V | | 2.5 | 4.5 | 7.0 | 2.2 | 7.8 | 8.2 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | | 2.4 | 3.7 | 5.2 | 2.1 | 5.9 | 6.2 | ns |
| | | $V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$ | | 2.3 | 3.4 | 4.6 | 1.9 | 4.9 | 5.1 | ns |
| C _L = 15 | pF | | | | | | | | | |
| t _{pd} | propagation delay | A, B and C to Y; see <u>Figure 13</u> | [2] | | | | | | | |
| | | V _{CC} = 0.8 V | | - | 31.6 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | | 3.4 | 8.0 | 15.7 | 3.1 | 16.7 | 17.0 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 2.8 | 5.7 | 9.4 | 3.1 | 10.4 | 10.9 | ns |
| | | V_{CC} = 1.65 V to 1.95 V | | 2.6 | 4.9 | 7.7 | 2.5 | 8.7 | 9.2 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | | 2.6 | 4.1 | 5.7 | 2.4 | 6.5 | 6.9 | ns |
| | | $V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$ | | 2.5 | 3.8 | 5.0 | 2.2 | 5.5 | 5.7 | ns |

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| Symbol | Parameter Conditions | | 25 °C | | | -4 | 0 °C to +1 | 25 °C | Unit | |
|-----------------------|----------------------|--|---------------|-----|--------|------|------------|----------------|-----------------|----|
| | | 1 | | Min | Typ[1] | Max | Min | Max (85 °C) | Max (125 °C) | |
| C _L = 30 | ρF | | | | | | | | | - |
| t _{pd} | propagation delay | A, B and C to Y; see <u>Figure 13</u> | [2] | | | | | | | |
| | | V _{CC} = 0.8 V | | - | 37.8 | - | - | - | - | ns |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | | 4.6 | 10.4 | 20.9 | 3.9 | 21.8 | 22.3 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 3.6 | 7.4 | 12.2 | 3.8 | 13.4 | 14.1 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | | 3.5 | 6.2 | 9.9 | 3.1 | 11.1 | 11.8 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | | 3.4 | 5.2 | 7.4 | 3.1 | 8.3 | 8.8 | ns |
| | | $V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$ | | 3.2 | 4.9 | 6.6 | 2.8 | 7.0 | 7.4 | ns |
| C _L = 5 pl | F, 10 pF, 15 pF and | 30 pF | | | | | | | | |
| C _{PD} | power dissipation | $f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ | <u>[3][4]</u> | | | | | | | |
| | capacitance | V _{CC} = 0.8 V | | - | 2.6 | - | - | - | - | pF |
| | | V _{CC} = 1.1 V to 1.3 V | | - | 2.8 | - | - | - | - | pF |
| | | V _{CC} = 1.4 V to 1.6 V | | - | 2.9 | - | - | - | - | pF |
| | | V _{CC} = 1.65 V to 1.95 V | | - | 3.1 | - | - | - | - | pF |
| | | V_{CC} = 2.3 V to 2.7 V | | - | 3.7 | - | - | - | - | pF |
| | | $V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$ | | - | 4.3 | - | - | - | - | pF |

Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit, see <u>Figure 14</u>.

[1] All typical values are measured at nominal $V_{\mbox{CC}}.$

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] All specified values are the average typical values over all stated loads.

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

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12. Waveforms

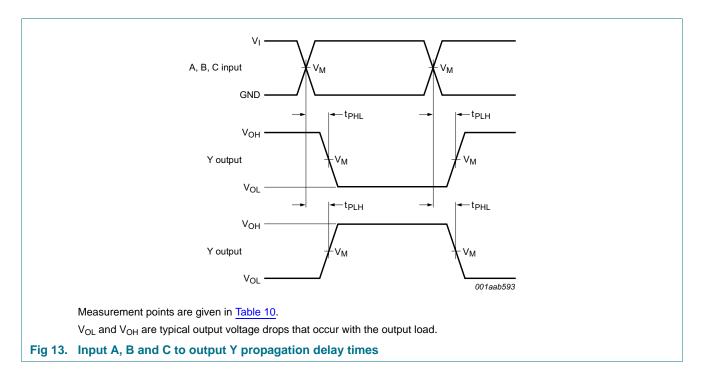


Table 10. Measurement points

| Supply voltage | Output | Input | | | | | |
|-----------------|--------------------|--------------------|-----------------|-------------|--|--|--|
| V _{cc} | V _M | V _M | VI | $t_r = t_f$ | | | |
| 0.8 V to 3.6 V | $0.5 	imes V_{CC}$ | $0.5 	imes V_{CC}$ | V _{CC} | ≤ 3.0 ns | | | |

Low-power configurable multiple function gate

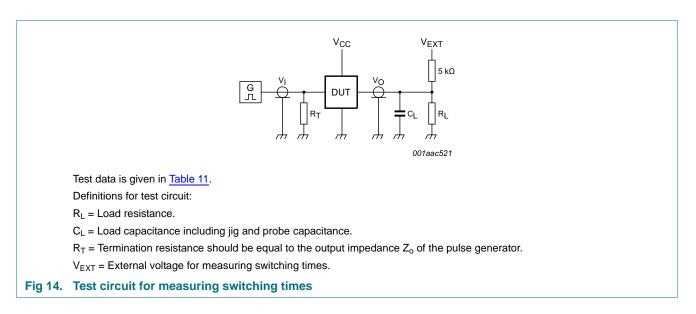


Table 11. Test data

| Supply voltage | Load | V _{EXT} | | | |
|-----------------|------------------------------|------------------------------|-------------------------------------|-------------------------------------|-------------------------------------|
| V _{cc} | CL | R _L [1] | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 k Ω or 1 M Ω | open | GND | $2 \times V_{CC}$ |

[1] For measuring enable and disable times, $R_L = 5 \text{ k}\Omega$. For measuring propagation delays, set-up and hold times, and pulse width, $R_L = 1 \text{ M}\Omega$.

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Low-power configurable multiple function gate

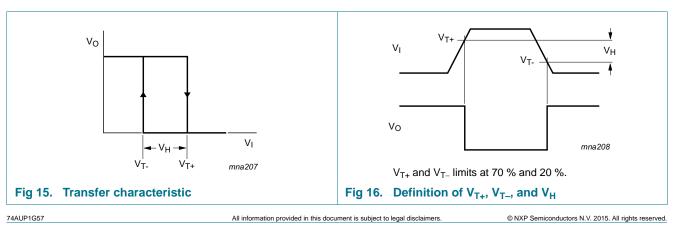
13. Transfer characteristics

Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 14</u>.

| Symbol | Parameter | Conditions | | 25 °C | | –40 °C to +125 °C | | | Unit | |
|---------------------|-------------------------------------|---|-----|-------|-----|-------------------|------|----------------|-----------------|---|
| | | | | n | Тур | Max | Min | Max (85 °C) | Max (125 °C) | |
| V _{T+} | positive-going threshold voltage | see <u>Figure 15</u> and Figure 16 | | | | | | | | |
| | | V _{CC} = 0.8 V | 0.3 | 0 | - | 0.60 | 0.30 | 0.60 | 0.62 | V |
| | | V _{CC} = 1.1 V | 0.5 | 3 | - | 0.90 | 0.53 | 0.90 | 0.92 | V |
| | | V _{CC} = 1.4 V | 0.7 | 4 | - | 1.11 | 0.74 | 1.11 | 1.13 | V |
| | | V _{CC} = 1.65 V | 0.9 | 1 | - | 1.29 | 0.91 | 1.29 | 1.31 | V |
| | | V _{CC} = 2.3 V | 1.3 | 7 | - | 1.77 | 1.37 | 1.77 | 1.80 | V |
| | | V _{CC} = 3.0 V | 1.8 | 8 | - | 2.29 | 1.88 | 2.29 | 2.32 | V |
| | negative-going threshold voltage | see <u>Figure 15</u> and Figure 16 | | | | | | | | |
| | | V _{CC} = 0.8 V | 0.1 | 0 | - | 0.60 | 0.10 | 0.60 | 0.60 | V |
| | | V _{CC} = 1.1 V | 0.2 | 6 | - | 0.65 | 0.26 | 0.65 | 0.65 | V |
| | | V _{CC} = 1.4 V | 0.3 | 9 | - | 0.75 | 0.39 | 0.75 | 0.75 | V |
| | | V _{CC} = 1.65 V | 0.4 | 7 | - | 0.84 | 0.47 | 0.84 | 0.84 | V |
| | | V _{CC} = 2.3 V | 0.6 | 9 | - | 1.04 | 0.69 | 1.04 | 1.04 | V |
| | | V _{CC} = 3.0 V | 0.8 | 8 | - | 1.24 | 0.88 | 1.24 | 1.24 | V |
| V _H hyst | hysteresis voltage | $(V_{T+} - V_{T-})$; see Figure 15, Figure 16, Figure 17 and Figure 18 | | | | | | | | |
| | | V _{CC} = 0.8 V | 0.0 | 7 | - | 0.50 | 0.07 | 0.50 | 0.50 | V |
| | | V _{CC} = 1.1 V | 0.0 | 8 | - | 0.46 | 0.08 | 0.46 | 0.46 | V |
| | | V _{CC} = 1.4 V | 0.1 | 8 | - | 0.56 | 0.18 | 0.56 | 0.56 | V |
| | | V _{CC} = 1.65 V | 0.2 | 7 | - | 0.66 | 0.27 | 0.66 | 0.66 | V |
| | | V _{CC} = 2.3 V | 0.5 | 3 | - | 0.92 | 0.53 | 0.92 | 0.92 | V |
| | | V _{CC} = 3.0 V | 0.7 | 9 | - | 1.31 | 0.79 | 1.31 | 1.31 | V |

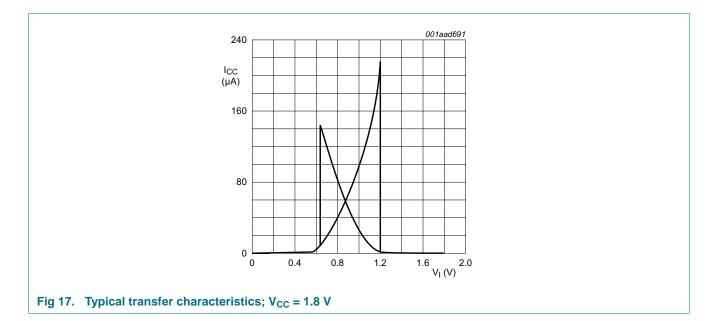
14. Waveform transfer characteristics

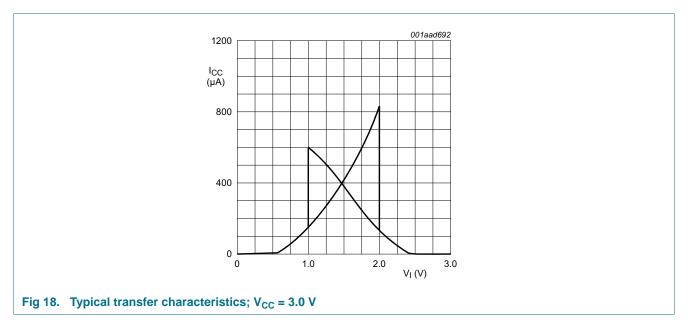


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15. Package outline

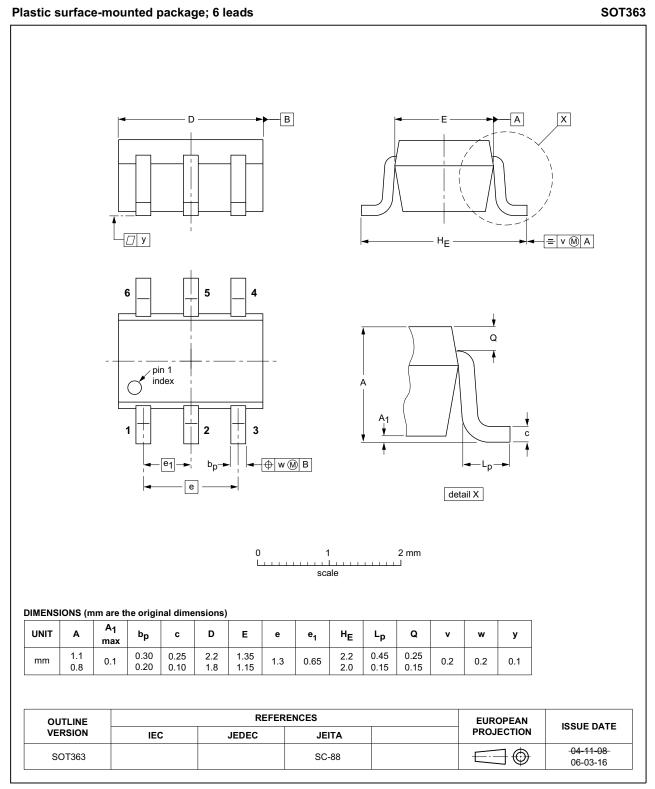


Fig 19. Package outline SOT363 (SC-88)

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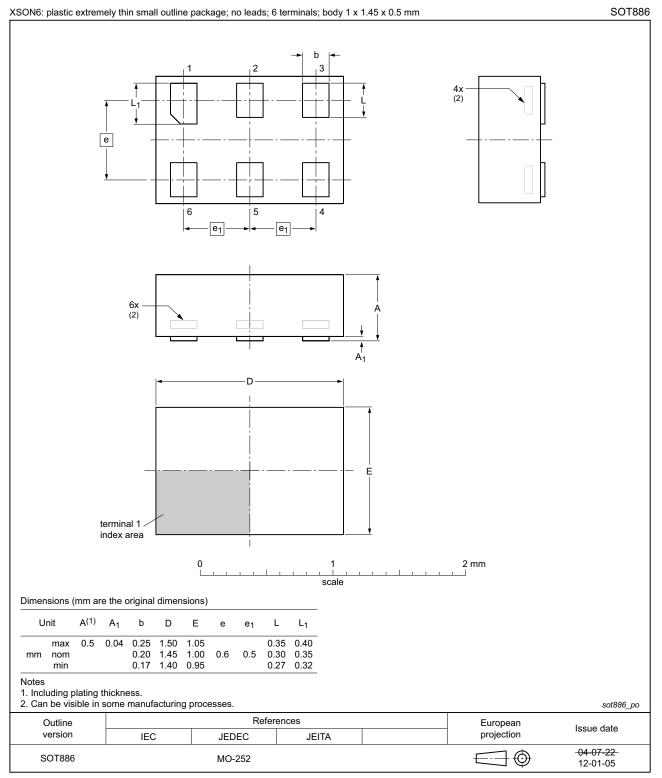


Fig 20. Package outline SOT886 (XSON6)

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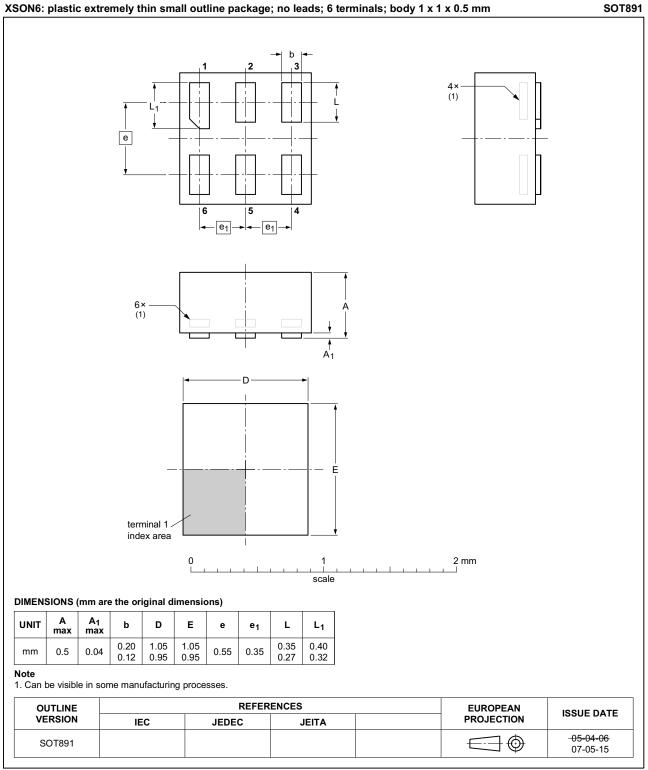
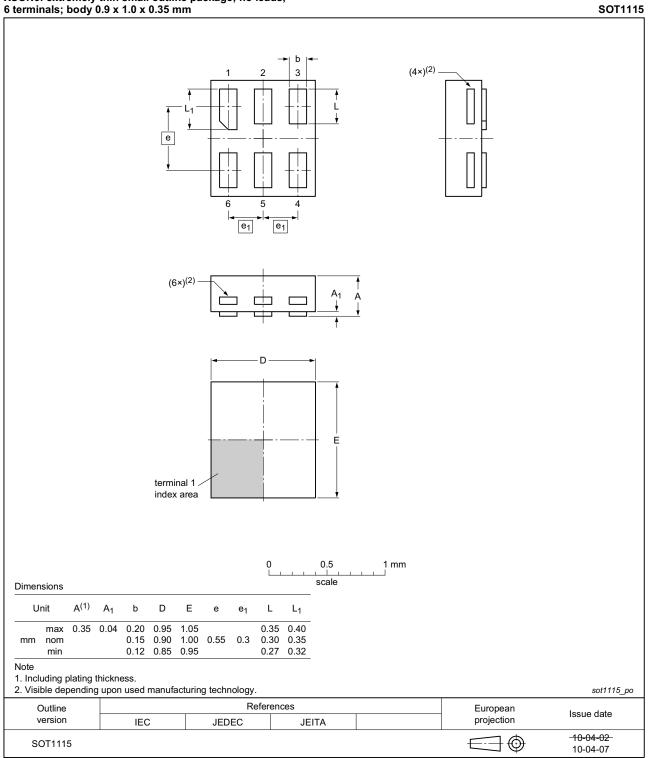


Fig 21. Package outline SOT891 (XSON6)

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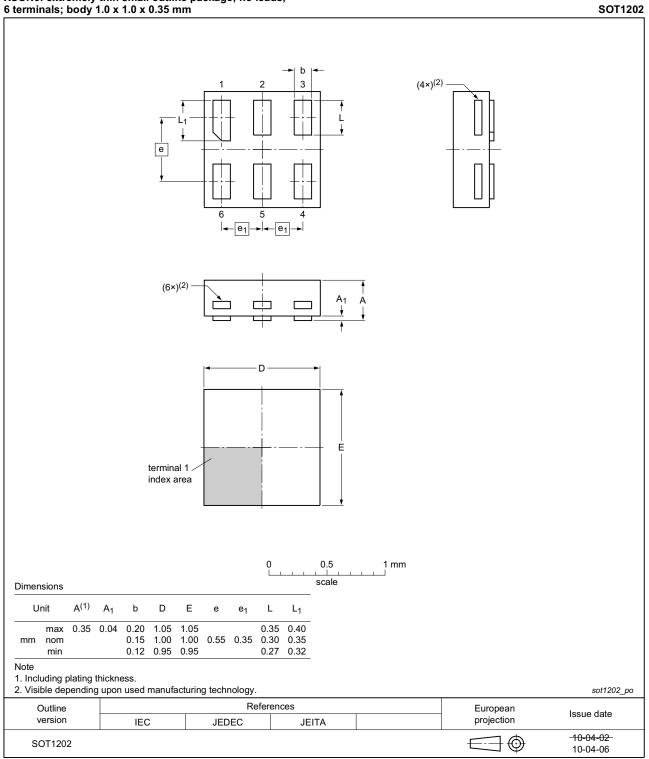


XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 22. Package outline SOT1115 (XSON6)

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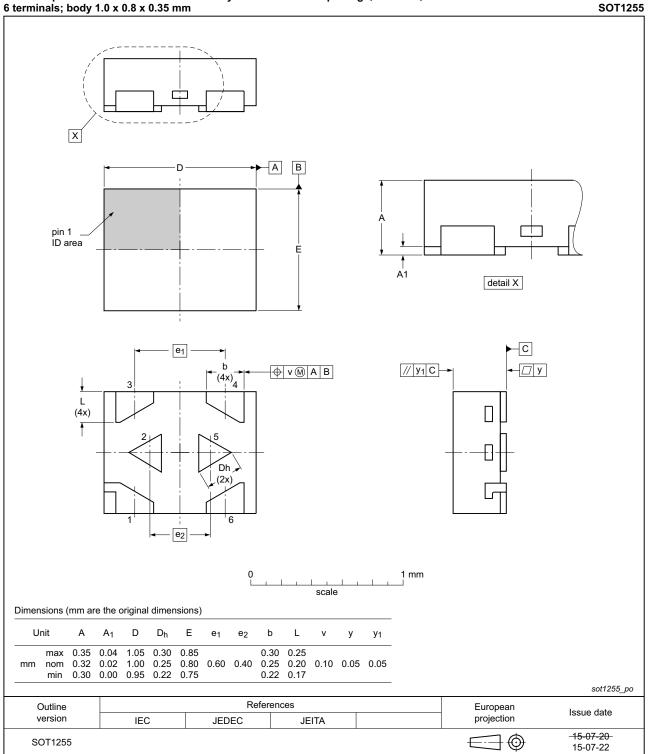


XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 23. Package outline SOT1202 (XSON6)

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X2SON6: plastic thermal enhanced extremely thin small outline package; no leads; 6 terminals; body 1.0 x 0.8 x 0.35 mm

Fig 24. Package outline SOT1255 (X2SON6)

74AUP1G57 **Product data sheet**

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16. Abbreviations

| Table 13. Abbreviations | | | |
|-------------------------|-------------------------|--|--|
| Acronym | Description | | |
| CDM | Charged Device Model | | |
| DUT | Device Under Test | | |
| ESD | ElectroStatic Discharge | | |
| HBM | Human Body Model | | |
| MM | Machine Model | | |

17. Revision history

Table 14.Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
|----------------|---|--------------------|---------------|---------------|--|
| 74AUP1G57 v.7 | 20150916 | Product data sheet | - | 74AUP1G57 v.6 | |
| Modifications: | Added type number 74AUP1G57GX (SOT1255/X2SON6). | | | | |
| 74AUP1G57 v.6 | 20120815 | Product data sheet | - | 74AUP1G57 v.5 | |
| Modifications: | Package outline drawing of SOT886 (Figure 20) modified. | | | | |
| 74AUP1G57 v.5 | 20111125 | Product data sheet | - | 74AUP1G57 v.4 | |
| 74AUP1G57 v.4 | 20100720 | Product data sheet | - | 74AUP1G57 v.3 | |
| 74AUP1G57 v.3 | 20090622 | Product data sheet | - | 74AUP1G57 v.2 | |
| 74AUP1G57 v.2 | 20090323 | Product data sheet | - | 74AUP1G57 v.1 | |
| 74AUP1G57 v.1 | 20061123 | Product data sheet | - | - | |

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18. Legal information

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| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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